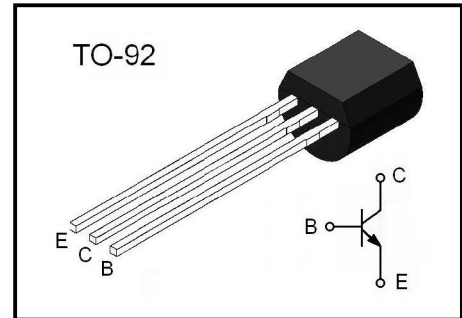


NPN Plastic-Encapsulate Transistors

Switching and Amplifier Applications

➤ Complement to BC640



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	BV_{CBO}	100	V
Collector-Emitter Voltage	BV_{CEO}	80	V
Emitter-Base Voltage	BV_{EBO}	5	V
Collector Current	I_C	1	A
Collector Power Dissipation	P_C	1	W
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55 ~ +150	°C

Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	BV_{CBO}	$I_C = 100\mu A, I_E = 0$	100			V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = 10mA, I_B = 0$	80			V
Emitter-base breakdown voltage	BV_{EBO}	$I_E = 100\mu A, I_C = 0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB} = 100V, I_E = 0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5V, I_C = 0$			0.1	μA
DC current gain	h_{FE}	$V_{CE} = 2V, I_C = 5mA$	25			
		$V_{CE} = 2V, I_C = 150mA$	40		160	
		$V_{CE} = 2V, I_C = 150mA$	100		250	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500mA, I_B = 50mA$			0.5	V
Base-Emitter On Voltage	$V_{BE(on)}$	$V_{CE} = 2V, I_C = 500mA$			1	V
Transition frequency	f_T	$V_{CE} = 5V, I_B = 10mA$		100		MHz

h_{FE} Classification

Classification	BC639-10	BC639-16
h_{FE} Range	40~160	100~250

Typical Characteristics

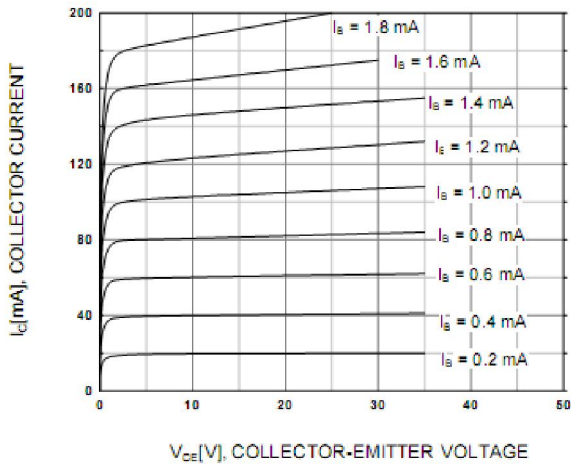


Figure 1. Static Characteristic

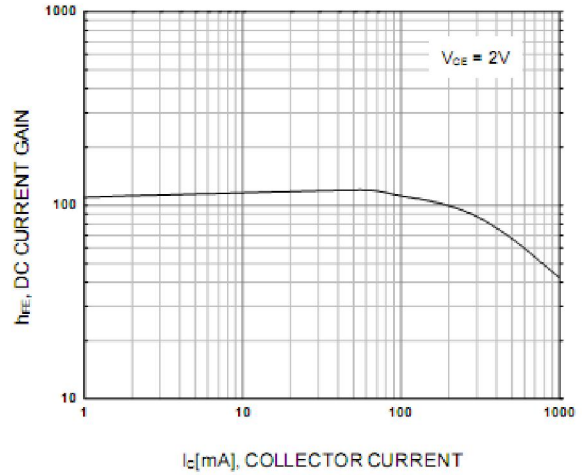


Figure 2. DC current Gain

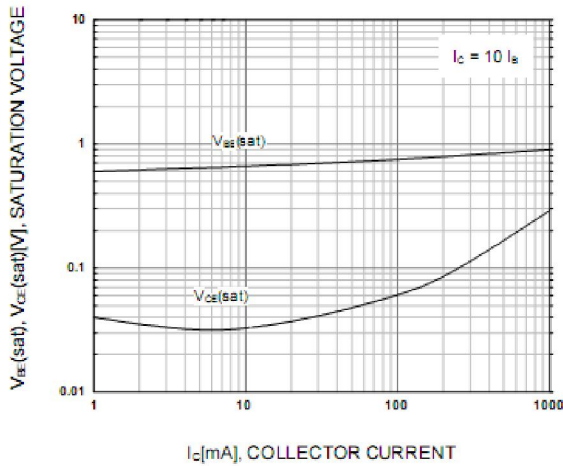


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

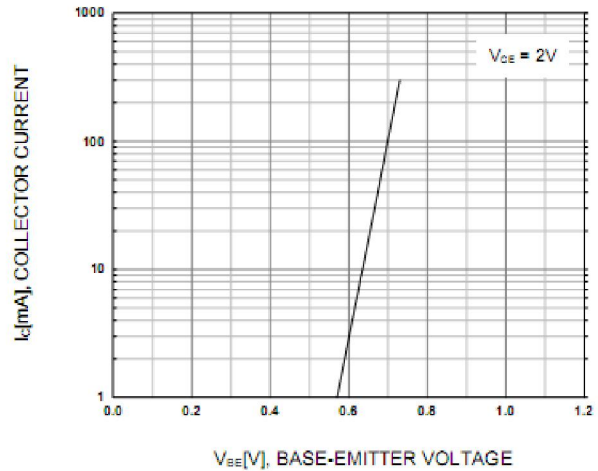


Figure 4. Base-Emitter On Voltage

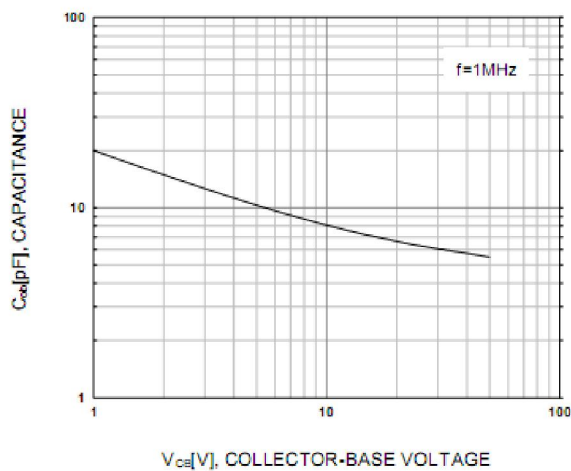


Figure 5. Output Capacitance

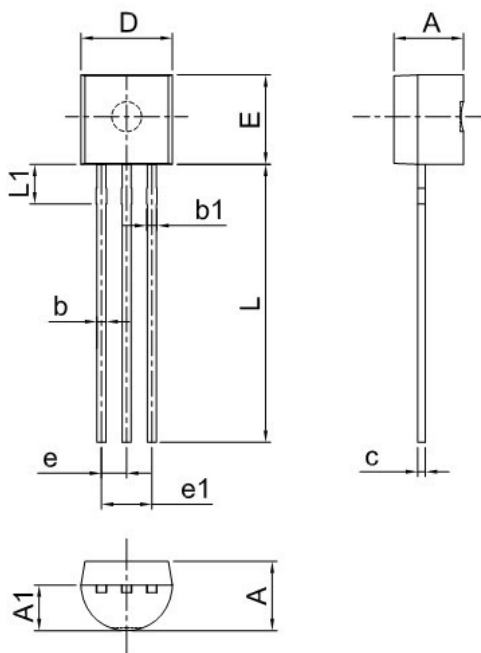
Ordering information

Package	Packing Description	Base Quantity
TO-92	Bulk	1000pcs/Bag
	Tape	2000pcs/Box

Package Dimensions

TO-92

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	3.30	3.70	0.130	0.146
A1	2.30	2.70	0.091	0.106
b	0.40	0.50	0.016	0.020
b1	0.50	0.70	0.020	0.028
c	0.35	0.45	0.014	0.018
D	4.45	4.70	0.175	0.185
E	4.40	4.65	0.173	0.183
e	1.17	1.37	0.046	0.054
e1	2.34	2.64	0.092	0.104
L	13.50	14.50	0.531	0.571
L1	1.80	2.20	0.071	0.087



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